

Supplementary Information

Crystal-Reconstructed BiVO₄ Semiconductor Photoelectrochemical Sensor for Ultra-Sensitive Tumor Biomarkers Detection

Yang Li,[†] Xianying Dai,[†] Lin He,[‡] Yuyu Bu*[†] and Jin-Ping Ao[†]

[†]Key Laboratory of Wide Band-Gap Semiconductor Materials and Devices, School of Microelectronics, Xidian University, Xi'an, 710071, China

[‡]Shanxi Provincial Cancer Hospital, Xi'an, 710061, China

1. Fabrication of PEC sensor and PEC detection equipment

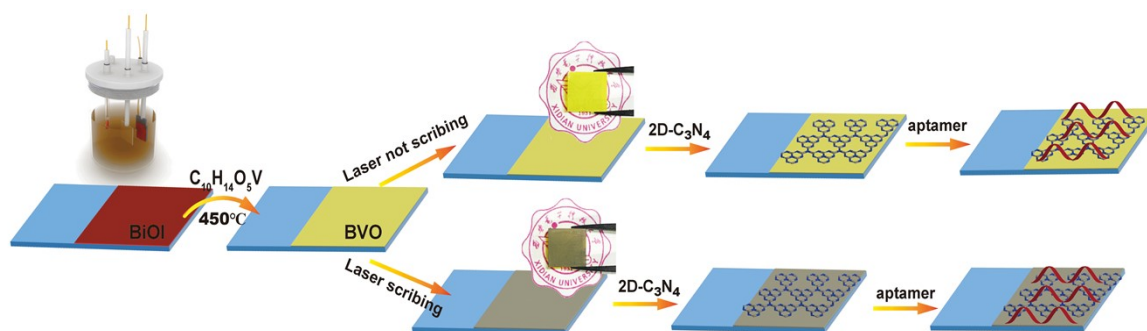


Figure S1. Preparation of the BVO and laser-BVO PEC sensors.

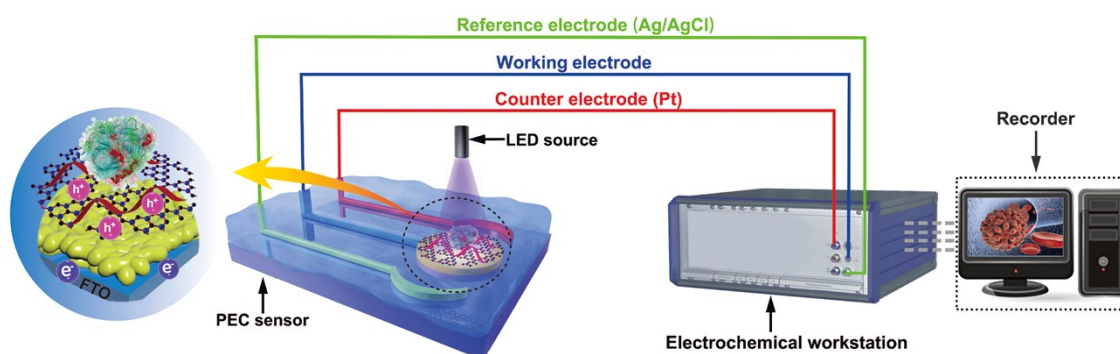


Figure S2. Photoelectrochemical analysis system for PSA specific detection

2. PEC performance of BiVO₄ (BVO) and laser treated BVO (laser-BVO) photoanodes.

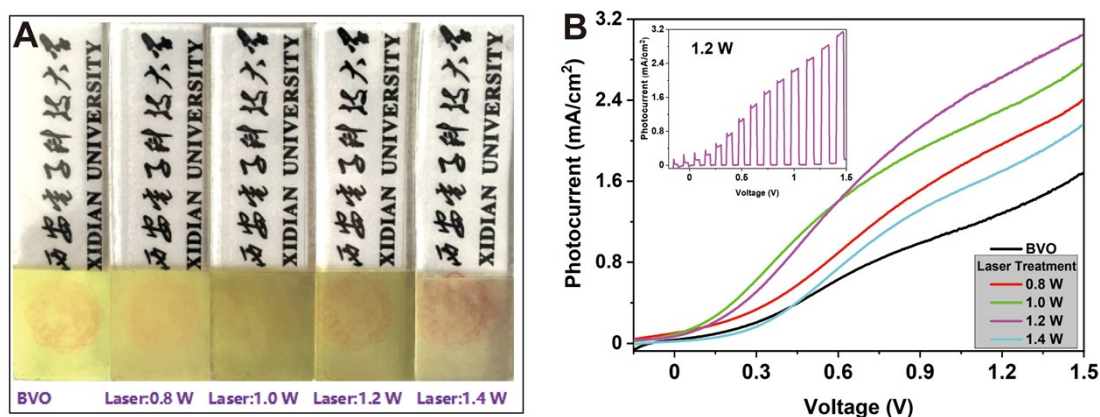


Figure S3. laser treated BiVO₄ photoanodes (A)The photographs and (B) photoinduced I-V curves of BVO photoanode and after laser treatment with different power density.

3. Fabrication of BVO/2D-C₃N₄ and laser-BVO/2D-C₃N₄ PEC biosensors

Because there isn't DNA aptamer probes sites on the surface of BVO semiconductor, in order to solve this problem, 2D-C₃N₄ with large $\pi=\pi$ electron cloud density was fixed on the surface of BVO and laser-BVO films for PSA DNA aptamer probes fixation. Figure S4A shows the photograph of the 2D-C₃N₄ powder sample and its dispersion liquid. The Faraday-Tyndall effect, which is known as light scattering phenomenon of particles in the suspension, can be clearly observed in the dispersion liquid, indicating that the dispersion contains 2D-C₃N₄ nanosheets. According to the HRTEM results shown in Figure S6B, it exhibits that 2D-C₃N₄ exists as an amorphous 2D sheet-like structure. Figure S4 (C and D) are the HRTEM images of BVO/2D-C₃N₄ and laser-BVO/2D-C₃N₄ after 2D-C₃N₄ modification. We can get the information that 2D-C₃N₄ layer clads closely on the surface of the BVO particle with a thickness of ~5 nm. Figure S4 (E and F) are the photoinduced I-V testing curves of BVO and laser-BVO photoanode after modifying of 2D-C₃N₄ with different amount. The outperformance of photoinduced I-V of BVO and laser-BVO photoanode are achieved by 180 μ L and 240 μ L 2D-C₃N₄ dispersion modification, respectively. Under this situation, the photogenerated carriers by BVO or laser-BVO can pass through the 2D-C₃N₄ cladding layer (~5 nm) via the tunneling effect, if the photocarriers pass through the 2D-C₃N₄, the reverse recombination probability of free electrons and holes would be suppressed remarkably. Meanwhile, the DNA aptamer probe can be fixed on the surface of BVO/2D-C₃N₄ by the cooperation of $\pi=\pi$ bonds on both of 2D-C₃N₄ and DNA aptamer without introduction of other fixation groups. Afterwards, we the important parameters (the incubation time and pH) were

optimized. As illustrated in Table S1 and S2, the 30 min and pH=7.4 were selected as the optimal binding time and pH value.

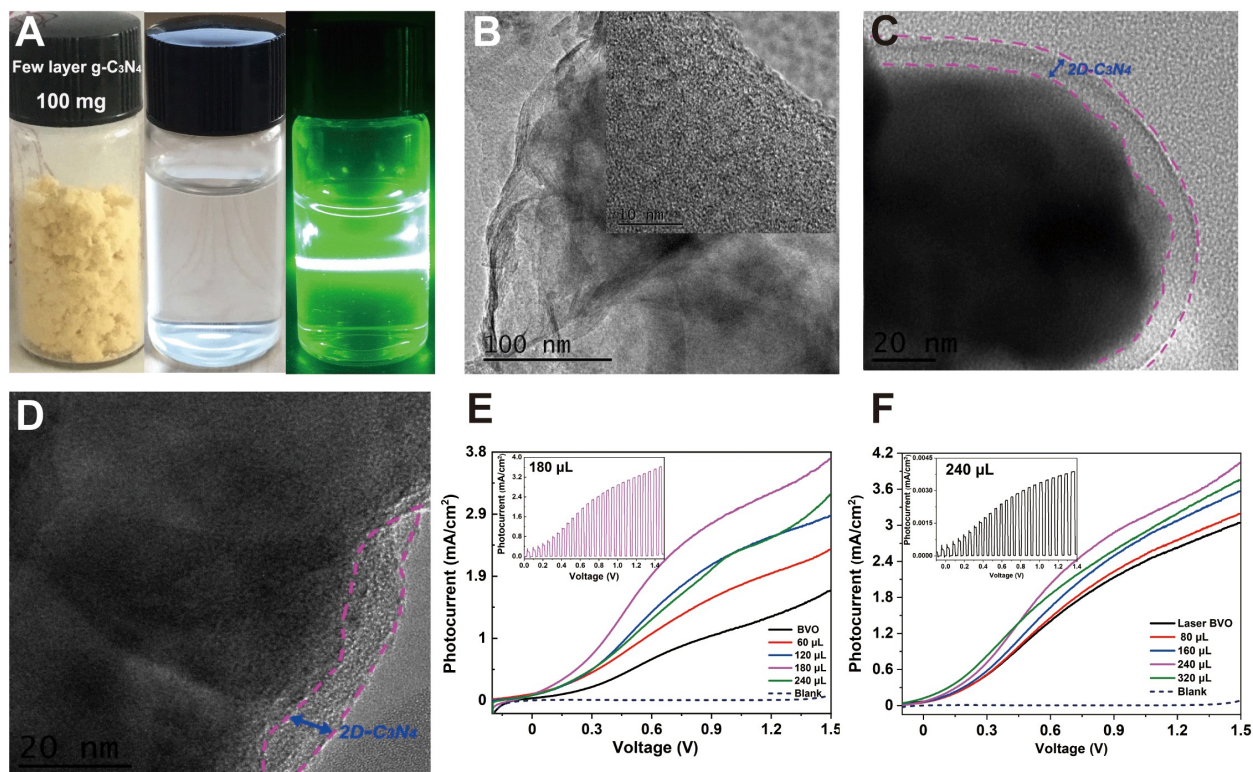


Figure S4. Dispersion, microstructure, and PEC characterizations of 2D-C₃N₄, BVO/2D-C₃N₄ and laser-BVO/2D-C₃N₄ photoanode. (A) Photograph of 2D-C₃N₄ sample and the corresponding dispersion liquid after of exfoliation. (B) and (C) HRTEM of 2D-C₃N₄, BVO/2D-C₃N₄ and laser-2D-C₃N₄. (E) and (F) photoinduced I-V curves of BVO/ 2D-C₃N₄ and laser-BVO/2D-C₃N₄ photoanodes.

Table S1. The optimization of conditions for BVO PEC sensor (the incubation time and pH)

Time (s) ΔCurrent (mA/cm ²) pH	6.6	7.0	7.4	7.8	8.2
10	0.02	0.04	0.04	0.14	0.03
20	0.22	0.22	0.23	0.21	0.22
30	0.29	0.33	0.35	0.31	0.23
40	0.29	0.33	0.34	0.35	0.33
50	0.29	0.33	0.34	0.33	0.32

Table S2. The optimization of conditions for laser-BVO PEC sensor (the incubation time and pH)

Time (s) ΔCurrent (mA/cm ²) pH	6.6	7.0	7.4	7.8	8.2
10	0.02	0.04	0.04	0.14	0.03
20	0.22	0.22	0.23	0.21	0.22
30	0.29	0.33	0.35	0.31	0.23
40	0.29	0.33	0.34	0.35	0.33
50	0.29	0.33	0.34	0.33	0.32

10	0.03	0.04	0.04	0.04	0.05
20	0.05	0.07	0.10	0.10	0.08
30	0.07	0.08	0.11	0.10	0.08
40	0.07	0.45	0.11	0.09	0.05
50	0.06	0.45	0.10	0.06	0.05

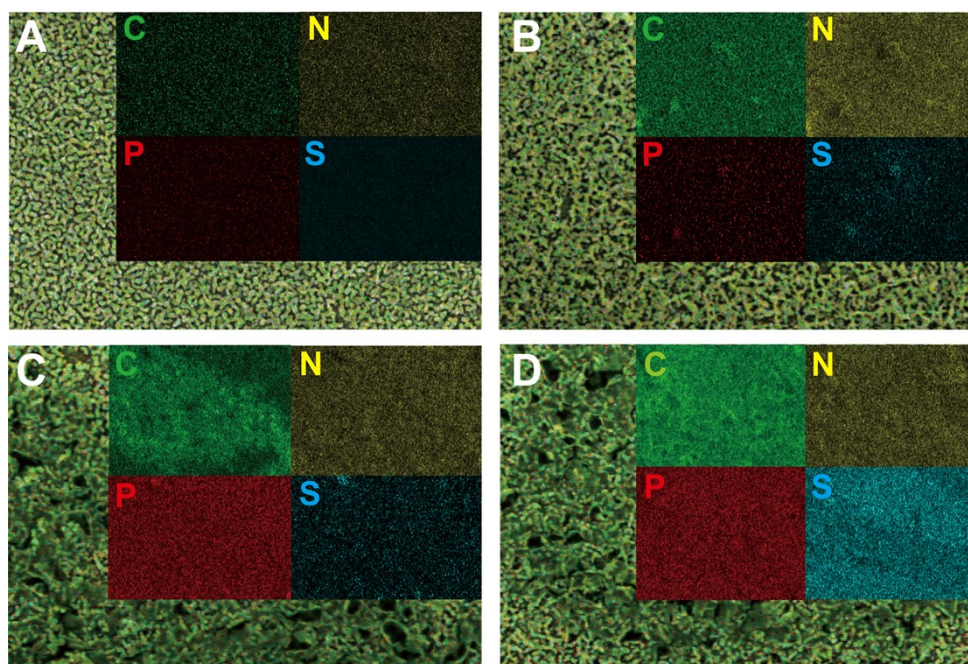


Figure S5. The energy-dispersive X-ray spectroscopy (EDS) mappings (C, N, P, S) of BVO PEC biosensor in different construction process (A) EDS mapping image of BVO thin film. (B) EDS mapping image of BVO /2D-C₃N₄ thin film. (C) EDS mapping image of BVO /2D-C₃N₄/ aptamer thin film. (D) EDS mapping image of BVO /2D-C₃N₄/aptamer/PSA thin film.

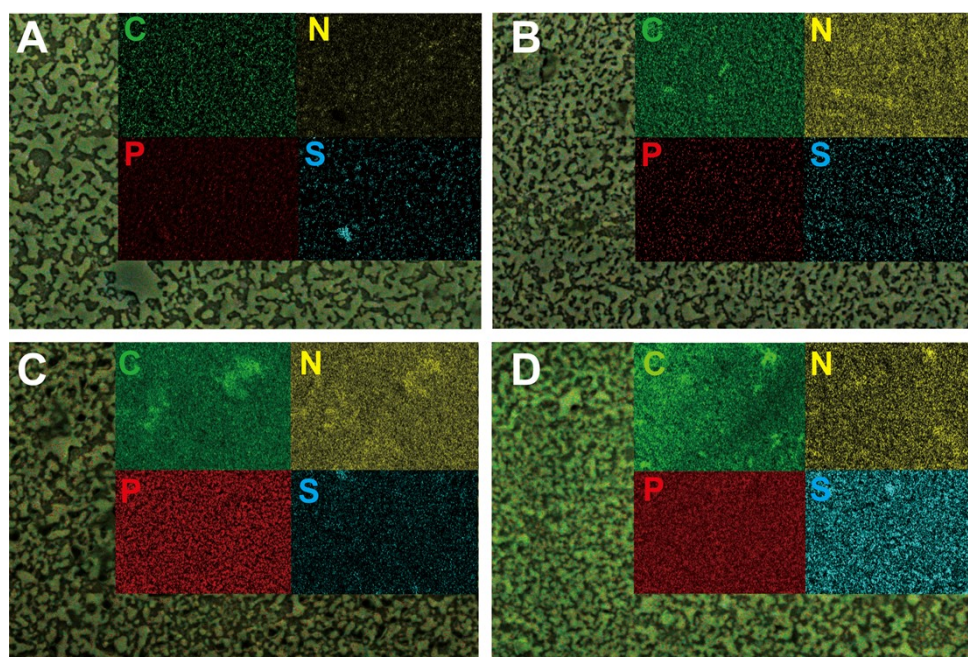


Figure S6. The energy-dispersive X-ray spectroscopy (EDS) mappings (C, N, P, S) of laser-BVO PEC biosensor in different construction process. (A) EDS mapping image of laser-BVO thin film. (B) EDS mapping image of laser-BVO /2D-C₃N₄ thin film. (C) EDS mapping image of laser-BVO /2D-C₃N₄/ aptamer thin film. (D) EDS mapping image of laser-BVO /2D-C₃N₄/aptamer/PSA thin film.

The energy-dispersive X-ray spectroscopy (EDS) mappings (C, N, P, S) of BVO and laser-BVO PEC biosensors in different construction process (in Figure S5 and S6). As shown in Figure.S7B, we can see the C-element and N-element are obviously increased on the BVO film surface after 2D-C₃N₄ modification, indicating the existence of 2D-C₃N₄ (compared to Figure S5A). Figure S5C)shows the mapping of 2D-C₃N₄/BVO, after DNA aptamer modification, the existence of P-element indicate that the aptamer chain was fixed on the 2D-C₃N₄/BVO electrode (because of DNA contains P-element). The mapping of aptamer/2D-C₃N₄/laser-BVO after targeting PSA (in Figure S5D) demonstrate that PSA was specifically binded and aptamer did not fall off the laser-BVO PEC sensor surface (because of PSA contains S-element and P-element did not decrease significantly). By using the similar method to the above, we can demonstrate that laser-BVO PEC is successfully constructed.

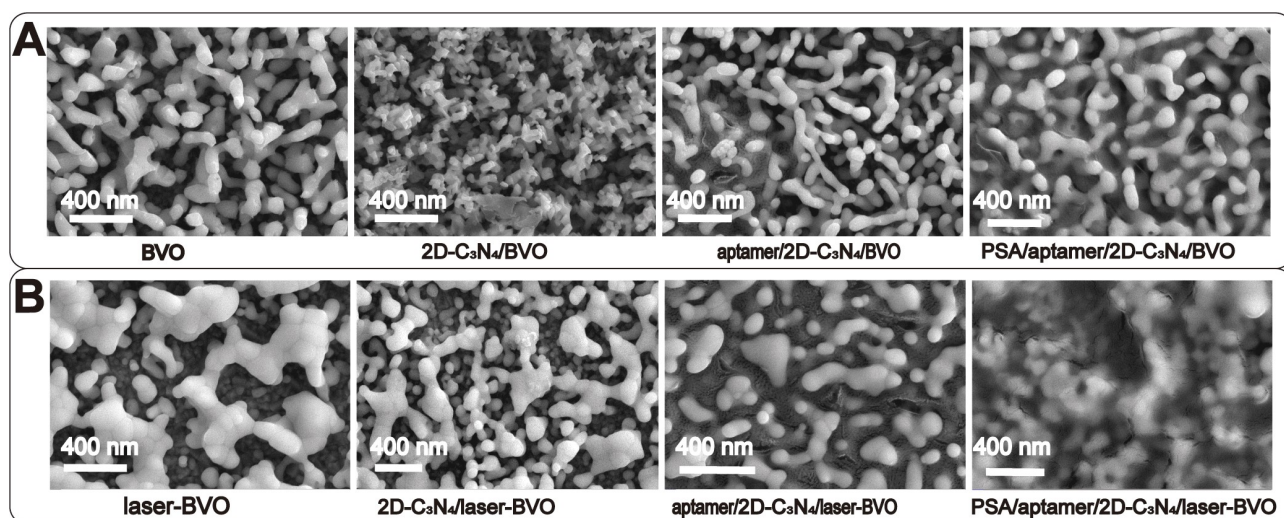


Figure S7. SEM of images of BVO and laser-BVO PEC biosensors in different construction process. (A) BVO PEC biosensor. (B) laser-BVO PEC biosensor.

4. Mechanism of the photocurrent inversion in laser-BVO PEC biosensor by DFT calculation

The calculation models BVO and laser-BVO (oxygen vacancy modified BVO, abb. Vo-BVO) have obtained by cutting and extending along the m-BiVO₄ (010) crystal plane (as shown in Figure

S10A). Figure S8 (B and C) present the band structure and the PDOS for both BVO and Vo-BVO crystal models. We can get the information that the band gap structure of the BVO moves to the vacuum level, meanwhile, a doping energy forms on top of the valence band (VB) and overlaps with the Femi-level (E_f) after oxygen vacancy doping in the BVO crystal. Then, the Femi-level of the BVO and Vo-BVO were calculated and the results showed in Figure S8D. The Femi-level energies of BVO and Vo-BVO locate at 6.88 eV and 5.66 eV, respectively. The upward Femi-level of Vo-BVO indicates that free electrons are released in the crystal by the breaking of the oxygen-metal bond. More importantly, as shown in Figure S8B, the doping band energy of Vo-BVO is equivalent to the corresponding Femi-level energy, thus, for the Vo-BVO PEC biosensor, the oxidation energy level of photogenerated holes will decrease to 5.66 eV. Figure S9 (A and B) show the PDOS and electrostatic potentials of BVO/CN and Vo-BVO/CN, we can see that, compared with BVO and Vo-BVO, the lowest occupied surface crystal orbital (LOSCO) of BVO/CN and Vo-BVO/CN shift negatively significantly, the Femi-level energies of BVO/CN and Vo-BVO/CN are 6.88 eV and 5.66 eV, respectively. The results indicating that the modification of 2D-C₃N₄ will further reduce the oxidation ability of holes. However, Because of the sintering temperature is low and 2D-C₃N₄ layer is about 5 ~10 nm (From Figure S4C and 4D) under this situation, the effect of heterojunction between BVO (or Vo-BVO) and 2D-C₃N₄ is not obvious. the photogenerated carriers by BVO or laser-BVO can pass through the 2D-C₃N₄ cladding layer via the tunneling effect. So we can ignore the effect band structure of 2D-C₃N₄ have on PSA.

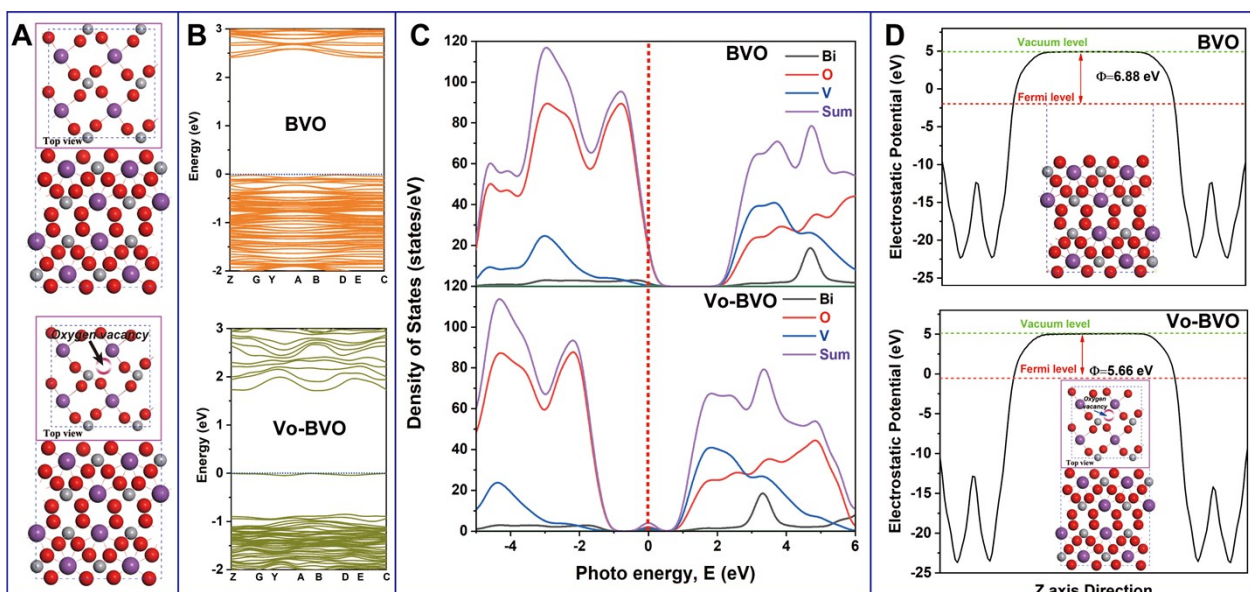


Figure S8. PDOS and electrostatic potentials of BVO and Vo-BVO. (A) Geometry model of BVO (010) and Vo-BVO (010); (B) PDOS of BVO and Vo-BVO; (C) The electrostatic potentials of BVO and Vo-BVO; (D) Fermi level potential of BVO and Vo-BVO.

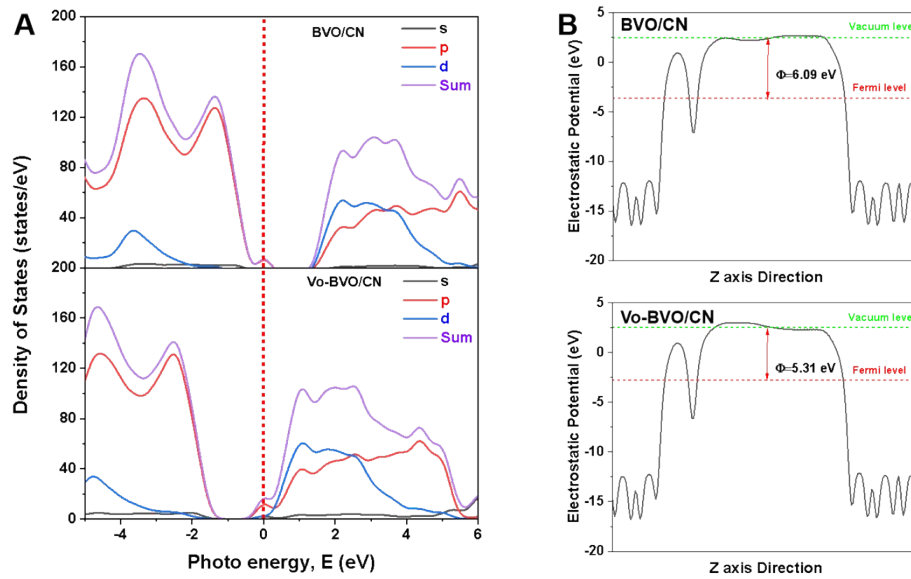


Figure S9. PDOS and electrostatic potentials of BVO/CN and Vo-BVO/CN. (B) PDOS of BVO/CN and Vo-BVO/CN; (C) The electrostatic potentials of BVO/CN and Vo-BVO/CN

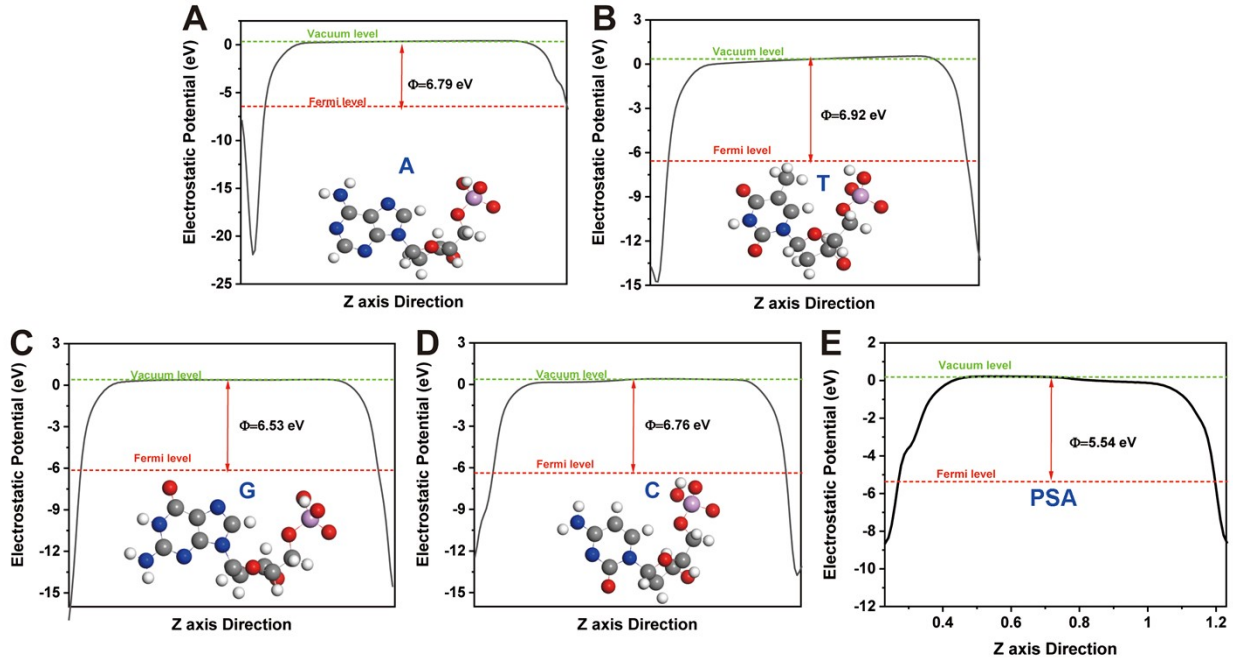


Figure S10. Calculation results of band structure and work function. (A) ~ (E) The work function of A, T, G, C, PSA respectively.

5. Optimization of the applied potential condition for BVO and laser-BVO PEC biosensor

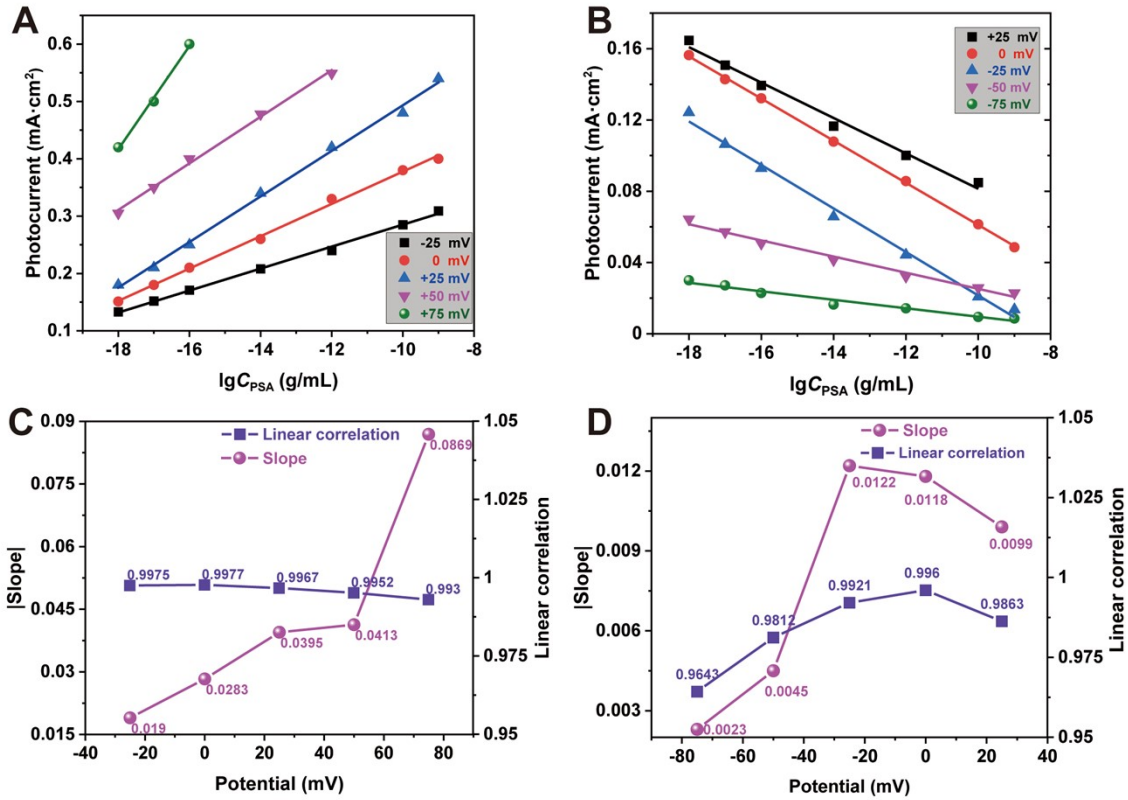


Figure S11. Optimum of the applied bias potential of the BVO and laser-BVO PEC biosensor. (A) and (B) Linear relationship between photocurrent and PSA concentration at different applied bias potential of BVO and laser-BVO PEC biosensor, respectively (vs. Ag/AgCl); (C) and (D) The |slope| and linear correlation of BVO and laser-BVO PEC biosensor at different applied bias potential.

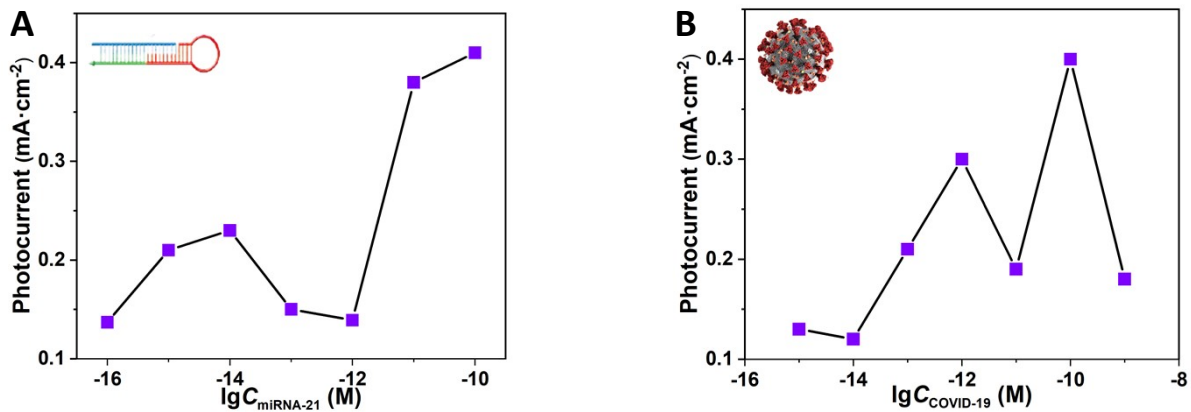


Figure S12. The detection results of BVO PEC biosensor. (A) For miRNA-21 detection; (B) For RdRp-COVID detection.

6. Mechanism of the high sensitivity and resolution rate of the BVO and laser-BVO PEC biosensors

Figure S13A is the optimized model structure of BVO and Vo-BVO crystal models. Compared with BVO, the surface atoms of Vo-BVO significantly shift, mainly because the oxygen atoms near the oxygen vacancies shift and move closer to the oxygen vacancies who take positive electricity. According to the adsorption optimization structure models (Figure S13B) of 2D-C₃N₄ covering on BVO and Vo-BVO crystal models, the surface atoms on Vo-BVO changes more dramatically than BVO after the contact with 2D-C₃N₄, and the fluctuation of 2D-C₃N₄ on Vo-BVO becomes larger than the counterpart also. Based on the above phenomenon, as shown in Figure S15A, the electron cloud overlap at 2D-C₃N₄ and Vo-BVO interface is more obvious, indicating a higher interaction between them. The model structure of the four bases (A, G, T, C) adsorbed by BVO/2D-C₃N₄ and Vo-BVO/2D-C₃N₄ are provided in Figure S13 (C and D). For bases can adsorb on the top of 2D-C₃N₄ layer with a near parallel state, there has letter effect on the atomic structure of 2D-C₃N₄ and BVO after bases adsorption.

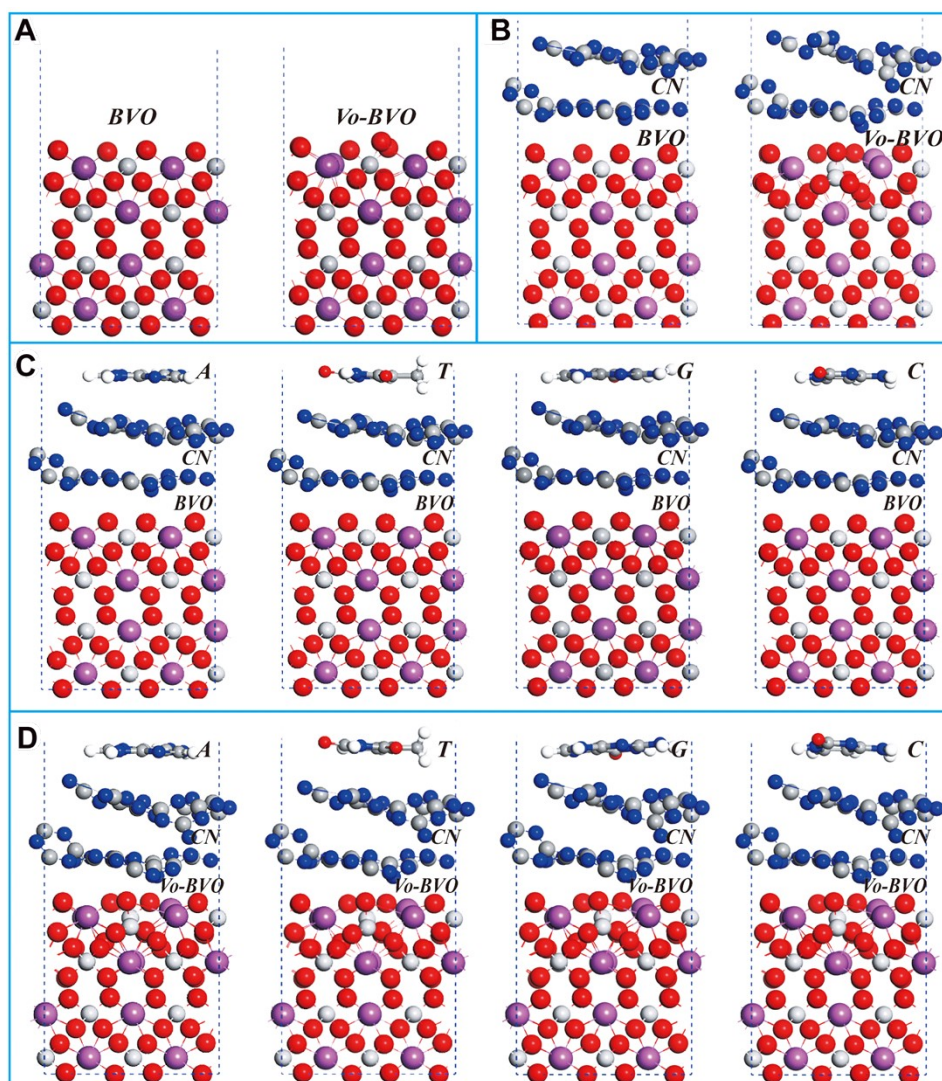


Figure S13. The DFT calculation model. (A) BVO and Vo-BVO simulation models after geometric optimization; (B) BVO/2D-C₃N₄ and Vo-BVO/2D-C₃N₄ simulation models after geometric optimization; (C) BVO/2D-C₃N₄/A, T, G, C simulation models after geometric optimization; (D) Vo-BVO /2D-C₃N₄/ A, T, G, C simulation models after geometric optimization.

Table S3. Fitted parameters of the EIS results based on the equivalent circuits.

		BVO		
		Samples	R_s	R_{et}
+25 mV	BVO		25.5 Ω	2.94 k Ω
	2D-C ₃ N ₄		24.1 Ω	1.96 k Ω
	Aptamer		23.8 Ω	2.41 k Ω
	1ng/mL PSA		25.6 Ω	1.50 k Ω
		laser-BVO		
		Samples	R_s	R_{et}
-25 mV	BVO		34.5 Ω	3.38 k Ω
	2D-C ₃ N ₄		39.4 Ω	3.61 k Ω
	Aptamer		31.1 Ω	4.15 k Ω
	1ng/mL PSA		34.2 Ω	4.88 k Ω

Table S4. Calculation data of τ_r , τ_{rec} from CIMPS and CIMVS results, respectively

		BVO			
Name		BVO	2D-C ₃ N ₄	aptamer	1 ng/mL PSA
f_{min} (CIMPS)		54.9 Hz	54.9 Hz	43.2 Hz	33.7 Hz
τ_r		2.90 ms	2.90 ms	3.68 ms	4.73 ms
f_{min} (CIMVS)		25.9 Hz	25.9 Hz	25.9 Hz	55.1 Hz
τ_{rec}		6.14 ms	6.14 ms	6.14 ms	2.89 ms
		Laser-BVO			
Name		Laser-BVO	2D-C ₃ N ₄	aptamer	1 ng/mL PSA
f_{min} (CIMPS)		173.1 Hz	109.8 Hz	87.5 Hz	69.5 Hz
τ_r		0.92 ms	1.45 ms	1.82 ms	2.29 ms
f_{min} (CIMVS)		25.9 Hz	25.9 Hz	25.9 Hz	25.9 Hz
τ_{rec}		6.14 ms	6.14 ms	6.14 ms	6.14 ms

7. The long-term storage of the BVO and laser-BVO PEC biosensors, the patient serum samples and patient information

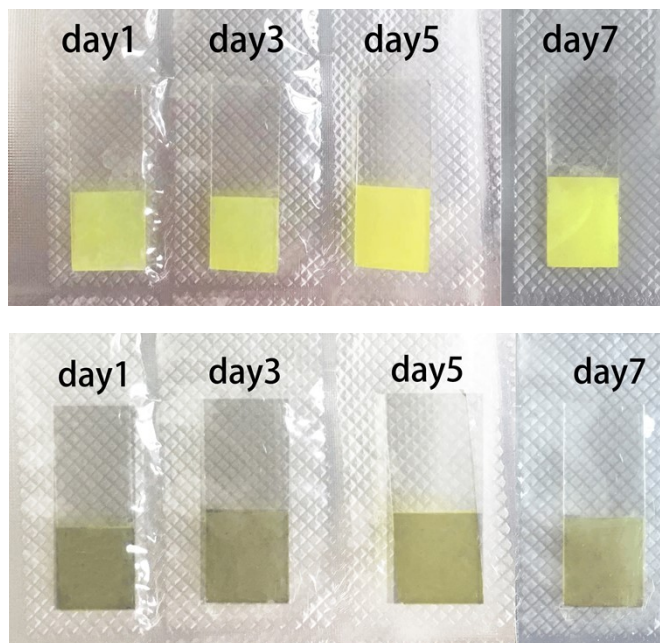


Figure S14. Photograph of sensor samples with sealed state.

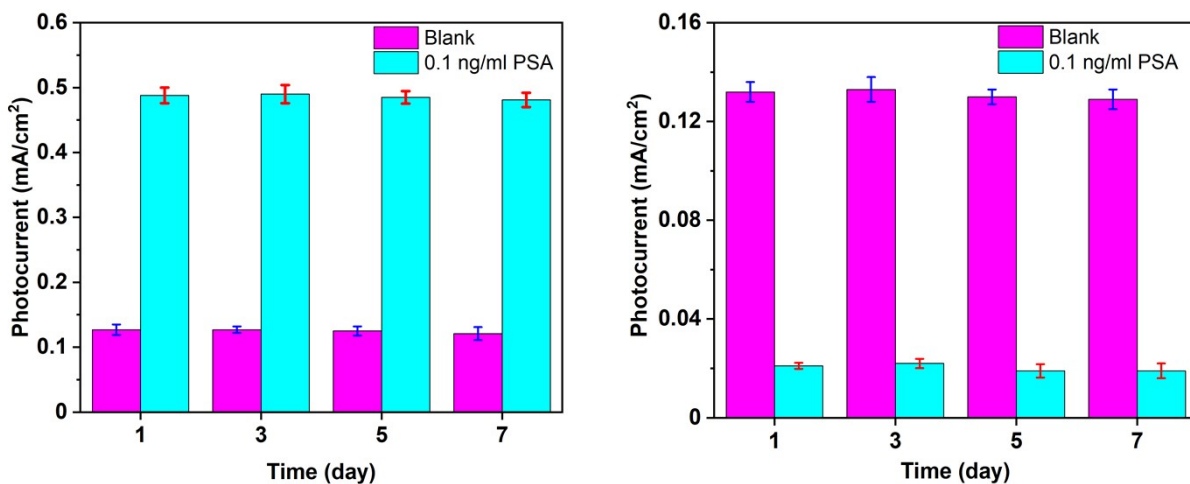


Figure S15. The long-term storage results of the BVO PEC biosensor and laser-BVO biosensor

Table S5. Patients' Information

Patient Code	Year	Gender	Diagnosis results	PSA levels (ng/mL)
1	85	Male	Prostate cancer	0.167
2	65	Male	Secondary malignant tumor of bone	1.12
3	83	Male	Prostate cancer	4.08
4	70	Male	Rectal cancer	10.59

5	66	Male	Lung cancer	1.03
6	64	Male	Kidney cancer	1.32
7	56	Male	Prostate cancer	15.86
8	73	Male	Prostate cancer	10.58